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Abstract

By monitoring changes in excitonic photolum inescence (PL) that are induced by terahertz (THz) radiation, we observe resonant THz absorption by magnetoexcitons in G aA s/A is aA s quantum wells. Changes in the PL spectrum are explored as a function of temperature and magnetic eld, providing insight into the mechanism s which allow THz absorption to modulate PL. The strongest PL-quenching occurs at the heavy hole 1s ! $2p^+$ resonance where heavy hole excitons are photo-therm ally converted into light hole excitons.

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Undoped quantum wells (QW) have been studied extensively using interband optical techniques (for examples, see Ref. 1). These experiments have revealed a rich structure which is dominated by correlated electron-hole pairs known as excitons. Excitons in square QW form hydrogen-like states with binding energy of approximately 10 m eV (the energy of a terahertz photon) and Bohr radius of 100 A. The internal dynam ics of excitons can be explored by using visible or near-infrared photons to create excitons, and THz radiation (of order 80 cm⁻¹, 10 m eV, 2.4 THz) to manipulate them directly. At low THz intensities, one expects direct transitions between even- and odd-parity states of the exciton which are not observable with linear interband spectroscopy. Such transitions provide new, sensitive tests for the theory of excitons, which is fundam ental in the physics of sem iconductors. At higher THz intensities, one also can probe the dephasing and energy relaxation rates of excitons.

Undoped direct gap (Type I) QW are especially interesting since they are so commonly used and provide a simple model system for theoretical analysis. However, the short lifetime of excitons in Type IQW makes it di cult to achieve the large population of cold excitons required for THz absorption studies. Experimental progress has been made in QW using photoinduced absorption in staggered (Type II) QW² and time-resolved THz spectroscopy in Type IQW ³ Optically-detected THz resonance (ODTR) spectroscopy was used to probe direct excitations of internal transitions of magnetoexcitons in Type IQW for the

rst tim $e_{\bullet}^{4,5}$ M ore recent work has included the study of charged ⁶^{{8}</sup> as well as neutral^{9;10} m agnetoexcitons in Type IQW .

Though ODTR has proven to be a powerful and successful technique, it remains an indirect measurement of THz absorption which still is not well understood. In this paper we use a multichannel technique to capture the fullPL spectrum as a magnetic eld sweeps exciton energy levels through THz resonances. We nd a combination of resonant and quasi-therm alexcitations are responsible for THz-induced changes in PL. In a particularly striking resonant process, THz radiation converts heavy-hole excitons (HX) to (radiative) light-hole excitons (LX).

The undoped sample consists of fty 100A -wide GaAs square QW between 150 A -wide A l_{1:3}G a_{1:7}A s barriers.¹¹ UCSB's Free-Electron Lasers (FEL) provide intense radiation (up to $1 \text{ MW}/\text{cm}^2$) that can be continuously tuned from 4 to 160 cm⁻¹ (0.5-20 meV, 0.12-4.8 THz). As shown in Fig. 1, visible radiation from an Ar⁺ laser is used to create electron-hole pairs in the undoped sam ple. Simultaneously, THz radiation with the electric eld polarized in the plane of the QW, and therefore not coupling to intersubband transitions, passes through the sample. M easurem ents are perform ed with a visible laser excitation intensity of approximately 100 W cm², creating an exciton density of approximately 3 10^{10} cm² per well in the sample.¹² The resulting PL is captured by eighteen 50 m diameter optic-bers that surround a central berused for excitation. The PL is delivered to a monochrom ator and detected by an image-intensi ed charge-coupled device (ICCD) camera. The output of the A r^{\dagger} laser is modulated acousto-optically to produce a 20 s visible excitation pulse that coincides with the 5 sTHz pulse at the sample. The ICCD is gated in time to capture the entire PL spectrum while the THz radiation pulse illum inates the sample. Since the THz pulse is much longer than any carrier relaxation time, the measurement is in steadystate. The PL change during the THz pulse is due to carrier excitation; no lattice heating is observed.¹³

The measurement involves monitoring the PL spectrum as a function of magnetic eld

B while xed frequency THz radiation illum inates the sample. Unlike a single channel measurements using a photo-multiplier tube, the ICCD allows the entire PL spectrum to be captured at each value of B. This powerful new technique is referred to as multichannel optically-detected THz resonance (MOTR). A separate MOTR run is made with the THz radiation blocked to serve as a reference.

Figure 2 shows the dierence of the PL spectra with and without THz irradiation plotted as a function of B. The THz frequency is 103 cm 1 and the intensity is approximately 50 kW /cm². The sample temperature is 10 K. Stronger PL quenching is represented by more negative values (shown in blue) of the PL di erence. The false color in age of this surface plot is projected on the bottom of the graph. There are strong qualitative di erences in the PL modulation at di event magnetic elds. Since experiments begin from B = 0 T, it is convenient to label the excitonic states using a hydrogenic notation (principal quantum number, orbital angular momentum, z-projection of the orbital angular momentum). At B = 0 T, the di erence spectrum shows the quenching of the heavy hole 1s (H 1s) PL peak amplitude (labeled A in Fig. 2), the enhancement of high energy tail of the H 1s PL (B), and the enhancement of the light hole 1s (L1s) PL amplitude (C). These e ects were previously observed and studied in detail.¹³ AsB increases, the H 1s PL amplitude is resonantly quenched at the H 1s! H $2p^+$ (m_z = +1) transition at 3.5 T (D and D'), while the L1s PL reaches a maximum (E and E'). The THz-induced transitions from H1s to L1s states is clearly seen. At 8 T, further resonant quenching is observed (F) which is assigned to the H 2p ($m_z = 1$)! H 2s transition. Note that above 3.5 T, quenching is reduced and the dominant e ect of THz radiation is to enhance and blueshift the H 1s PL peak (F). This can seen in the depth (height) of the PL di erence surface plot above and below 3.5 T and is is also shown by the color di erence between these two regions in the projected in age plot. A ridge that begins at 1.58 eV at 0 T and appears to follow the quadratic magnetic eld dependence of the H 1s PL peak also is indicated (G). This ridge is consistently higher than the H 1s state by one THz photon energy throughout the magnetic eld range. Note that this ridge appears to cross a more strongly curved second ridge at point E', which is where the L1s is resonantly enhanced. Neither ridge is consistent with magnetic eld dependence of PL from the L1s. Also note that the line where the PL di erence sheet crosses zero (yellow line in the projected in age plot) is nearly independent of magnetic eld and does not follow the B^2 dependence of H 1s PL peak energy.

The inform ation contained in Fig. 2 is more accessible when cross-sections through this surface plot are exam ined. The resonant enhancement of the L1s PL peak at the expense of the H 1s PL am plitude is shown in Fig. 3(b), where the H 1s and L1s PL am plitudes are plotted against B. Note that this gure shows the PL am plitudes, not the normalized PL ratios (i.e., PL with divided by PL without THz inradiation, as shown in most OD TR spectra), which adds a baseline that depends on B. The H 1s ! H 3p feature at 2.1 T splits into two dips (H 1s ! H 3p⁺ and H 1s ! H 3p) above 2.5 T. $\frac{4^{i5}i^{14}}{16}$ The L1s PL enhancement is asymmetric in B, with a fast decay above 3.5 T, and a more gradual decrease below 3.5 T. The H 1s am plitude shows sim ilar asymmetry and recets the conventional OD TR results.^{4,5} Figure 3(a) sketches the energy di erence between the H 1s and higher energy exciton states (based on data published in Ref. 4). The diagram s in the inset of Fig. 3 (a) sketch the phototherm al carrier distributions at di erent magnetic elds, and will be discussed in greater detail later in this paper.

Absorption of THz radiation can heat carriers, resulting in a quasi-therm all distribution with a temperature above that of the lattice.¹³ It is thus useful to compare changes in photolum inescence induced by THz radiation to those induced by changing the temperature of the sample. Figure 4 plots the L1s to H1s PL amplitude ratio as a function of inverse lattice temperature, without (a) and with (b) THz irradiation of approximately 100 W cm². These data form A menius plots where straight lines indicate therm ally activated population of the L1s from H1s states. The slopes of these lines determ ine the activation energies, which are shown in the legends of Fig. 4. Note the dram atic decrease in the activation energy when the sample is illum inated by THz radiation at 3.5 T.

We propose a qualitative explanation of THz-induced changes in PL which involves three processes. 1. Absorption: THz radiation is absorbed via internal transitions of excitons,^{4;5;14;6;10} or by D rude-like free carrier excitations of ionized electrons and holes.¹³ 2. Quasi-thermalization: Each species of excitons (for example, H 1s, H 2p⁺, or L1s), is associated with a band of states with di errent center-of-mass momenta. The power transferred into the electron-hole system indirectly heats each band of excitons to a temperature warm er than that of the lattice. 3. Lum inescence: The lum inescence under THz irradiation only relects the population of states that can participate in radiative interband transitions. In bands with even parity (1s, 2s, for example), the radiative states are those with in-plane momentum K_{COM} near zero. In bands with odd parity, such as 2p, no states are radiative.

We now discuss the experimental data as a function of increasing magnetic eld with a xed THz frequency of 103 cm¹. The case B = 0 T has been studied extensively in Ref. 13. In this nonresonant case, the mechanism for absorption was shown to be D nude-like heating of ionized electrons and holes. These hot electrons and holes heat lum inescing excitons. The non-resonant photo-therm all distribution is represented by the cartoon on the left side of the inset in Fig. 4 (a). Under THz illum ination, the exciton system (including both H 1s and L1s excitons) could be reasonably well described by a single temperature larger than that of the lattice. This temperature could be measured by matching the PL spectrum with THz irradiation at a low lattice temperature to the PL spectrum without THz radiation at an elevated lattice temperature. A seither temperature or THz power increases, the magnitude of H 1s lum inescence decreases, and the L1s/H 1s PL ratio increases. Either of these quantities could be used to measure the temperature of the exciton system . Both measures produce consistent results.¹³

Between 0 T and about 3.5 T, the qualitative features of Figs. 2 and 3 are similar to those at B = 0, with a quenching of the H 1s lum inescence and enhancement of L1s. In this regime, there are many internal states which have energies below that of the 103 cm⁻¹ pump, and which can be excited by it.

One of the most striking features of the data is the resonant transfer of PL from H 1s to L1s which occurs near 3.45 T (E and E' in Fig. 2, also Fig. 3). Our explanation is a resonant photo-therm alm echanism, shown schem atically in the central cartoon in the inset of Fig. 4 (a). THz radiation promotes excitons from H 1s to H $2p^+$. The dark H $2p^+$ state¹⁵ is only about 1 m eV below the radiative L1s state according to PL and ODTR data. Therm al

uctuations, associated with the quasi-tem perature of the H $2p^{\dagger}$ excitons, are su cient to then populate L 1s exciton states to a much greater degree than they could be populated via therm alexcitation directly from H 1s. A coording to photo-therm alionization experiments on shallow donors in G aA s,¹⁶ the $2p^{\dagger}$ state allows extrem ely e cient ionization. Reference 16

found that the probability of ionization from the 2p state is much larger than expected from the energy separating this state and the continuum; the ionization probability at 4.2 K is essentially unity.¹⁷ L1s excitons decay, em itting the observed lum inescence. The photothem al hypothesis is supported by the observation that, in F ig. 4 (b), the ratio of L1s to H 1s lum inescence is nearly independent of tem perature for the case of T H z on, B = 3.45 T. This demonstrates an elective activation energy which is negligible. In contrast, without T H z irradiation, the L1s/H 1s at 3.45 T increases strongly with temperature, consistent with an activation energy on the order of 10 m eV.

A second hypothesis is that the THz radiation heats the entire exciton system e ciently on resonance, but that all bands of excitons can still be described with a single tem perature. W e call this the them al hypothesis. The them al hypothesis could be consistent with the insensitivity of the L1s /H1s ratio to increasing temperature at resonance. However, it predicts that, as was observed for B=0 T, the photolum inescence spectrum under THz illum ination at low temperatures can be mapped onto the photolum inescence spectrum without THz excitation at some higher temperature. This is not the case. At 3.45 T and at a lattice temperature of 10 K with THz illum ination of 110 kW /cm², the H1s PL amplitude is the same as for a lattice temperature of 70 K without THz illum ination at 3.45 T.However, the L1s peak for the cold sam ple illum inated with THz is over 40% larger than for the unillum inated warm sample. Furthmerm ore, the L1s PL amplitude increases linearly with THz intensity at the H1s! H2p⁺ resonance, while the increase in the absence of THz illum ination is consistent with exponentially activated behavior as a function of temperature. This is consistent with the photo-therm al hypothesis, and inconsistent with the therm al hypothesis.

Above 3.45 T, the changes in photolum inescence induced by THz irradiation are qualitatively di erent from those induced at lower magnetic elds. At high magnetic elds in Fig. 3(a), the THz photon energy is smaller than the lowest dominant exciton transition (H 1s! H $2p^+$). The high magnetic eld photo-therm all distribution is shown schematically in the cartoon on the right side of the inset in Fig. 3 (a). In this regime, lower energy exciton transitions (e.g., H 2p ! H 2s) can occur, and the hot carriers can impact with and heat cold excitons, which produces a PL quenching signal at 8 T in Fig. 2. The heating is not e cient and high THz and visible intensities are required to produce the H 2p ! H 2s feature. There are several reasons for this reduced e ciency. First, at low tem perature, most of the carriers are bound in 1s (ground state) excitons, so the population in excited states (e.g., 2p which has an energy that has a characteristic temperature of 80 K above the 1s state), especially at low THz and visible intensities, is signi cantly lower than the 1s population. Higher intensities increase the exciton temperature, and hence enhance the population of 2p excitons that can participate in the H 2p ! H 2s transition. Second, PL am plitudes are not as sensitive to tem perature changes at higher B. Finally, most hot heavy hole excitons (HX) (with center of m ass m on enture $K_{COM} \in 0$) will eventually cool to contribute to the m ain HX PL line within the radiative cone (K $_{COM}$ 0). Since radiative recombination for the hot HX (K COM 6 0) is suppressed due to m om entum conservation, and since non-radiative recombination is weak, most of the hotter HX have now here to go but back to the $K_{COM} = 0$ state where they can e ciently recombine radiatively. The closest escape for HX is the L1s which is over 14 m eV (163 K) higher in energy at B = 0 (see Fig. 3(a)). This activated behavior can be seen in Fig. 4, where the activation energy to populate the L1s state is

approximately 10 m eV without (a) and with (b) THz irradiation at 8 T.As a result, heating may increase the H 1s lifetime as it journeys through K_{COM} -space, but will not signicantly change the quantum end ciency of the H 1s PL nor the steady-state ODTR signal.

This model does not explain the THz-induced enhancement and blueshift of the H 1s PL amplitude. One expects an energy shift in the PL close to THz resonances due to the ac Stark e ect.¹⁸ The calculated shift changes sign depending on whether the THz frequency is higher or lower than the transition frequency. The data, on the other hand, show a shift that increases monotonically with B. The lack of a sign change may be due to the fact excitonic transition energies are swept across the energy of the photons in the strong THz radiation eld. As a result the detuning frequency is not xed, but is swept from positive to negative values, and hence no single laser induced energy shift is observed.

MOTR has been used to study the THz dynamics of magnetoexcitons in GaAsQW. Excitonic transitions have been identied and are in good agreement with theory. A simple qualitative model can be used to understand the PL modulation due to THz radiation. On the other hand, this work has generated several new puzzles which still require exploration. The MOTR baseline and the higher energy ridge (labeled G in Fig. 2) that follows the H 1s peak are still not clearly understood. The higher energy ridges (G and E' in Fig. 2) appear to indicate mixing of excitonic and photonic states. Signi cant energy shifts of over 3 m eV are observed in the H 1s PL close to H 2p ! H 2s, which may be related to an ac Stark elect. The information gained from studying excitons in QW will provide an important foundation for research of excitons in even lower dimensional systems such as quantum wires and dots.

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FIGURES

FIG.1. A schem atic of the experim ental setup for $M \circ TR$ m easurem ents. Photolum inescence is detected while the THz pulse passes through the sample. The THz radiation is polarized parallel to the plane of the QW. The tim ing of the laser pulses and PL is shown in the lower half of the gure.

FIG.2. PL spectra without THz irradiation subtracted from PL spectra with THz irradiation at 103 cm 1 as function of B. The THz intensity is approximately 50 kW cm 2 . The sample temperature is 10 K.

FIG.3. Energies relative to the H 1s state of higher energy excitonic states are schem atically shown in (a). Solid lines indicate energy levels (e.g., H $2p^+$) that are accessible from the H 1s state via radiative transitions. W hen B = B $_{1s-2p^+}$, the THz photon energy matches the H 1s! H $2p^+$ energy separation. Note that for B > 3:5 T, the H $2p^+$ state is above the L1s state. Inset in (a) are simple representations of the therm al and photo-therm al carrier distributions induced by THz irradiation. The L1s and H 1s PL am plitudes are plotted as a function of B under THz illum ination at 10 K in (b). These data are obtained from cross-sectional slices that follow the L1s and H 1s PL energies in Fig.2.

FIG.4. A mhenius plot of the L1s/H 1s ratio without (a) and with (b) THz invadiation. The THz intensity is approximately 100 kW cm². The straight lines represent activated behavior with an activation energy that is determined by the slope of the line. A ctivation energies that are obtained from exponential ts are shown in the legends. The L1s-H 1s energy spacing measured from PL is approximately 14 m eV for all B. The H $2p^+$ -L1s separation is approximately 1 m eV at 3.45 T.